

US009228273B2

## (12) United States Patent

Keszler et al.

(10) **Patent No.:** 

US 9,228,273 B2

(45) **Date of Patent:** 

Jan. 5, 2016

# (54) NONLINEAR OPTICAL CRYSTALS AND THEIR MANUFACTURE AND USE

(75) Inventors: **Douglas A. Keszler**, Corvallis, OR (US);

Ning Ye, Fujian (CN)

(73) Assignee: State of Oregon acting by and through

the State Board of Higher Education on behalf of Oregon State University,

Corvallis, OR (US)

(\*) Notice: Subject to any disclaimer, the term of this

patent is extended or adjusted under 35

U.S.C. 154(b) by 1072 days.

(21) Appl. No.: 13/301,538

(22) Filed: Nov. 21, 2011

(65) Prior Publication Data

US 2012/0063475 A1 Mar. 15, 2012

## Related U.S. Application Data

- (63) Continuation of application No. 11/765,406, filed on Jun. 19, 2007, now Pat. No. 8,062,420, which is a continuation-in-part of application No. 11/107,367, filed on Apr. 14, 2005, now abandoned.
- (60) Provisional application No. 60/562,881, filed on Apr. 16, 2004, provisional application No. 60/562,626, filed on Apr. 14, 2004.
- (51) Int. Cl.

  C30B 29/22 (2006.01)

  C30B 9/00 (2006.01)

(Continued)

(58) Field of Classification Search CPC .... C30B 29/22; G01F 1/3551; C09K 11/7712 USPC ........... 252/301.4 R, 301.5; 372/21; 423/263; 117/950 See application file for complete search history.

## (56) References Cited

## U.S. PATENT DOCUMENTS

4,231,838 A 11/1980 Gier 4,791,927 A 12/1988 Menger (Continued)

### FOREIGN PATENT DOCUMENTS

RO 1298217 6/2001 WO WO 00/015731 3/2000 (Continued)

## OTHER PUBLICATIONS

Peshev et al, "A new solvent for the Growth of Y1-xNdxAl3(BO3)4 single crystals from high-temperature solutions", Journal of Crystal Growth, 144, 1994, Dec. II, No. 3/4, pp. 187-192.\*

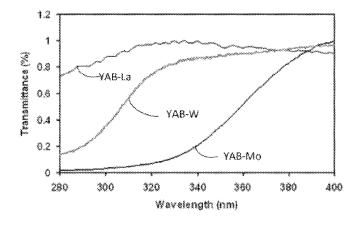
(Continued)

Primary Examiner — Carol M Koslow (74) Attorney, Agent, or Firm — Klarquist Sparkman, LLP

### (57) ABSTRACT

Described are nonlinear optical (NLO) crystals, including aluminum-borate NLO crystals, that have low concentrations of contaminants that adversely affect the NLO crystal's optical properties, such as compounds that contain transition-metal elements and/or lanthanides, other than yttrium, lanthanum, and lutetium. Some NLO crystals with low concentrations of these contaminants are capable of second harmonic generation at very short wavelengths. Also described are embodiments of a method for making these NLO crystals. Some embodiments involve growing a single NLO crystal, such as an aluminum-borate NLO crystal, from a mixture containing a solvent that is substantially free of harmful contaminants. The described NLO crystals can be used, for example, in laser devices.

### 11 Claims, 1 Drawing Sheet



(51)	Int. Cl.	
	C09K 11/77	(2006.01)
	C30B 9/12	(2006.01)
	C30B 17/00	(2006.01)
	C30B 29/10	(2006.01)
	G02F 1/355	(2006.01)

## (56) References Cited

#### U.S. PATENT DOCUMENTS

4,826,283 5,030,851 5,130,996 5,202,891 5,684,813 5,879,803	A A A A	7/1991 7/1992 4/1993 11/1997	Chuangtian et al. Unternahrer et al. Amano et al. Sleight et al. Keszler Masaki et al.
5,879,803	A	3/1999	Masaki et al.
6,238,593 6,419,855	В1	7/2002	Huguenin et al. Keszler et al.
8,038,904 2004/0060501	A1	4/2004	Alekel
2005/0247918 2006/0054864 2008/0014135	A1		Keszler et al. Alekel et al. Alekel

#### FOREIGN PATENT DOCUMENTS

WO WO 03/105238 12/2003 WO WO 2004/007352 1/2004

## OTHER PUBLICATIONS

Leonyuk et al, "Grwoth and Characterization of RM3(BO3)4 Crystals", Prog. Crystal Growth and Charact. vol. 31, 1995, pp. 179-192.\* Beregi E. et al., "Growth and Morphology of Nd<sup>3+</sup>, Er<sup>3+</sup>and Cr<sup>3+</sup>doped YAl<sub>3</sub> (BO<sub>3</sub>)<sub>4</sub> Single Crystals," *Cryst. Res. Technol.* 34(45-6):641-645, 1999.

Brenier A., "Tunable Coherent Infrared Generation Near 2.5 µm from Self-Difference Frequency Mixing in YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>:Nd<sup>3+</sup>," Appl. Opt. 43:6007-6010, 2004.

Chen, C. et al., "Recent Advances in Nonlinear Optical and Electro-Optical Materials," *Ann. Rev. Mater. Sci.* 16:203-243, 1986.

Dekker et al., "Continuous wave and Q-switched diode-pumped neodymium, lutetium: yttrium aluminum borate lasers," *Optics Communications* 151:406-412, 1998.

Dekker et al., "2.27-W Q-switched self-doubling Yb:YAB laser with controllable pulse length," *J. Opt. Soc. Am. B* 22(2):378-384, Feb. 2005

Durmanov S.T. et al. "Binary rare-earth scandium borate for diodepumped lasers," *Optical Materials* 18:234-284, 2001.

Feigelson R.S., Byer R.L., Route R.K. and Joo G-t., "Search for New Nonlinear Optical Materials," *Center for Nonlinear Optical Materials Annual Report*, C.3., 3 pages, 1995.

Gruber et al., "Spectroscopic properties of nonlinear NdSc<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>", *Journal of Applied Physics* 87(10):7159-7163, May 15, 2000.

Jia G. et al., "Growth and Thermal and Spectral Properties of a New Nonlinear Optical Crystal TmAl<sub>3</sub>(BO<sub>3)4</sub>," *Crystal Growth and Design* 5(3):949-952, 2005.

Jung et al., "Phase Transition of Neodymium Yttrium Aluminum Borate with Composition," *Materials Research Bulletin* 31(8):1021-1027, 1996.

Kellendonk F et al., "On the Luminescence of Bismuth, Cerium, and Chromium and Yttrium Aluminium Borate," *J. Chem. Phys* 76(3):1194-1201, 1982.

Keszler, D. A., "Borates for optical frequency conversion," *J. Current Opinion in Solid State & Materials Science* 1:204-211, 1996.

Koporulina, E.V. et al., "Flux growth of (Y,RE)A13(BO<sub>3</sub>)<sub>4</sub> solid solutions (RE=Nd, Gd. Ho, Yb, Lu)," *Journal of Crystal Growth* 211(1-4):491-496, Apr. 1, 2000.

Kuz'min O.V. et al. "Cerium scandium borate—an active nonlinear medium for diode-pumped lasers," *Quantum Electronics* 28(1):50-54, 1998.

Leonyuk et al., "Entrance of impurities into yttrium aluminum borate crystals," Izvestiia Akademii nauk SSR, Neorganicheskie materialy, 12(7):249-1251, 1976.

Leonyuk N. I. and Leonyuk L.I., "Growth and Characterization of RM<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> Crystals," *Prog. Crystal Growth and Charact*. 31:179-278, 1995.

Li, J. et al., "The influence of Yb<sup>3+</sup>concentration on Yb:Al<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>," *Cryst. Res. Technol.* 38(10):890-895, 2003.

Lu et al., "Excited Emission and Self-Frequency-Doubling Effect of Nd<sub>x</sub> Y<sub>1-x</sub>Al<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> Crystal," *Chinese Physics Letters* 3(9):413-416, 1986

Meyn, J. et al., "Spectroscopic Properties and Efficient Diode-Pumped Laser Operation of Neodymium-Doped Lanthanum Scandium Borate," *J. of Quantum Electronics* 30(4):913-917, 1994. Mills A.D., "Crystallographic Data for New Rare Earth Borate Compounds, RX<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>," *Inorg. Chem* 1:960-961, 1962.

Nikolov, V. et al., "A New Solvent for the Growth of Y1-XNDXAL<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> Single Crystals from High-Temperature Solutions," *Journal of Crystal Growth* 144(3/04):187-192, Dec. 2, 1994. Ostroumov, V. et al., "Crystal growth, spectroscopic and laser characterization of Nd: CSB crystals," *J. of Luminescence* 72-74:826-828, 1997.

Peterson, G. A., "Studies on New Solid-State Inorganic Borates and Oxoanion Fluorides." Chapter 1, pp. 1-7, 1999 Ph.D. Thesis.

Peterson, G. A. et al., "Trigonal Huntite Borate CeSc<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>(CSB)," Chapter 2, pp. 14-32, 1999 Ph.D. Thesis.

Peterson G.A., Keszler D.A., and Reynolds T.A., "Stoichiometric, trigonal huntite borate CeSc<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>," *Intern. J. Inorg. Mater.* 2:101-106, 2000.

Peterson, Dr. G. A., "Huntite Crystals for UV Nonlinear Optics and Self-Doubled Lasers," *Scientific Materials Corp.*, (Abstract Ballistic Missile Defense Organization Counsel, 2001.).

Supplementary European Search Report dated Jan. 19, 2009.

Wang, P. et al., "Growth and evaluation of ytterbium-doped yttrium aluminum borate as a potential self-doubling laser crystal," *J. Opt. Soc. Am. B.*, 16(1):63-69, Jan. 1999.

Ye, N. et al., "Nonlinear Optical Crystal Y<sub>x</sub>La<sub>y</sub>Sc<sub>2</sub>(BO<sub>3</sub>)<sub>4</sub>(x+y+z=4)," *Chem. Mater.* 17:2687-2692, 2005.

Ye, N. et al., "Growth of nonlinear optical crystal Y<sub>0.57</sub>La<sub>0.72</sub> Sc<sub>2.71</sub>(BO<sub>3</sub>)<sub>4</sub>," *J. of Crystal Growth* 292:464-467, 2006.

\* cited by examiner

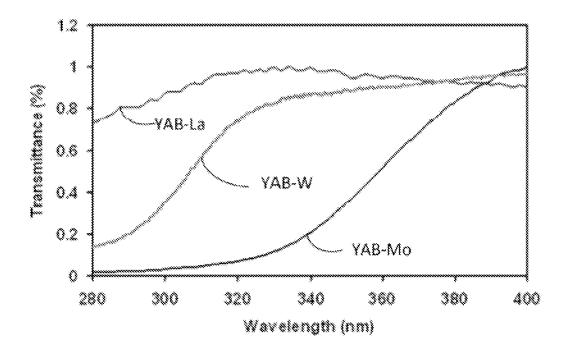


FIG. 1

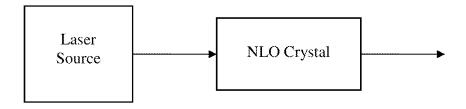


FIG. 2

## NONLINEAR OPTICAL CRYSTALS AND THEIR MANUFACTURE AND USE

# CROSS-REFERENCES TO RELATED APPLICATIONS

This application is a continuation of U.S. patent application Ser. No. 11/765,406, filed on Jun. 19, 2007, which is a continuation-in-part of U.S. patent application Ser. No. 11/107,367, filed Apr. 14, 2005, which claims the benefit of the earlier filing date of U.S. Provisional Application No. 60/562,881, filed Apr. 16, 2004, and U.S. Provisional Application No. 60/562,626, filed Apr. 14, 2004, which is incorporated by reference herein. Subject matter for all claims herein is disclosed in U.S. Provisional Application No. 60/562,626.

## STATEMENT AS TO RIGHTS TO INVENTIONS MADE UNDER FEDERALLY SPONSORED RESEARCH OR DEVELOPMENT

This invention was made in part using funds provided by the National Science Foundation Grant No. ECS-0114017. The United States Government has certain rights in this invention.

#### **FIELD**

Disclosed embodiments concern nonlinear optical crystals, particularly nonlinear optical crystals having reduced 30 amounts of certain contaminants relative to known nonlinear optical crystals, such as contaminants that interfere with the optical properties of the nonlinear optical crystals.

## BACKGROUND OF THE INVENTION

The optical properties of nonlinear optical (NLO) materials are modified by light passing through the materials. The modification of the optical properties may be caused by an induced electronic charge displacement (polarization) that 40 acts as an oscillating dipole. The oscillating dipole may cause the material to emit a photon. When the polarization of the material is linear, the emitted photon has the same frequency as the light incident upon the material. If the polarization is nonlinear, the frequency of the light emerging from the mate- 45 rial may be some integer value times the frequency of the incident light. For example, the net effect of frequency doubling is that two photons with a frequency  $\Omega$  combine to generate a single photon having a frequency equal to  $2\Omega$ . Thus, propagation of the waves in synchronization (phase- 50 matching) allows the light's frequency to double. Frequency doubling also is referred to as second harmonic generation (SHG). NLO materials were discovered to be capable of second harmonic generation in 1961. Ann. Rev. Mater. Sci., 16:203-43 (1986).

Several NLO materials have been recognized in the prior art. For example, YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> NLO crystals are disclosed in Pu Wang ET AL., *Growth And Evaluation Of Ytterbium-Doped Yttrium Aluminum Borate as a Potential Self-Doubling Laser Crystal*, J. OF THE OPTICAL SOC. OF AM. B, 60 January 1999, at 63-69, which is incorporated herein by reference. NLO crystals, such as YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> NLO crystals, have been used in a variety of devices. For example, U.S. Pat. No. 5,202,891 describes a neodymium yttrium aluminum borate NLO crystal incorporated into a laser device. U.S. Pat. No. 65 4,826,283 describes another NLO device made from single crystals of LiB<sub>3</sub>O<sub>5</sub>.

2

It is known to recrystallize NLO materials to form larger crystals with uniform crystal structures. For example, J. Li ET AL. disclose the formation of YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> NLO crystals from a flux containing K<sub>2</sub>MoO<sub>2</sub>. See J. Li ET AL., *The Influence of Yb*<sup>3+</sup> *Concentration on Yb:YAl*<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>, 38 CRYS. RES. TECH. 890-895 (2003), which is incorporated herein by reference. Aluminum-borate NLO crystals grown with conventional techniques are generally limited to the generation or emission of light at wavelengths greater than 370 nm.

#### BRIEF SUMMARY OF THE INVENTION

Described herein are nonlinear optical (NLO) crystals that have reduced concentrations of compounds that adversely affect the crystal's optical properties relative to known NLO crystals. These undesirable compounds are present to varying degrees in conventional NLO crystals, particularly conventional aluminum-borate NLO crystals. Some of the disclosed crystals are useful for modifying the wavelength of incident light, such as light emitted by a laser. For example, some of the disclosed crystals are capable of converting an input laser beam of a first wavelength into an output laser beam of a second wavelength, where the second wavelength is some integer value of the incident wavelength and is less than about 300 nm, typically less than about 250 nm, typically less than about 200 nm, and even more typically less than about 175 nm.

Some of the disclosed crystals have volumes greater than about 0.1 mm<sup>3</sup>, typically greater than about 1 mm<sup>3</sup>, and even more typically greater than about 5 mm<sup>3</sup>. These crystals comprise a primary material and can also comprise one or more secondary materials different from the primary material. In some embodiments that contain secondary materials, any secondary materials that interfere with the generation and/or emission of light at desired wavelengths are present at low concentrations relative to their concentrations in conventional NLO crystals. For example, the secondary materials that interfere with the generation and/or emission of light at desired wavelengths can be present at concentrations of less than about 100 ppm by weight, typically less than about 50 ppm by weight, and even more typically less than about 10 ppm by weight. In other embodiments, the crystals are substantially free of secondary materials that interfere with the generation and/or emission of light at desired wavelengths. The secondary materials that interfere with the generation and/or emission of light at desired wavelengths can be, for example, compounds than contain transition-metal elements and/or lanthanides, other than yttrium, lanthanum, and lutetium. Some of these secondary materials, however, such as tungsten, are present in useful solvents and have a limited effect on the generation and/or emission of light at certain desired wavelengths. In some embodiments, the crystal comprises less than about 100 ppm by weight, typically less than about 50 ppm by weight, and even more typically less than about 10 ppm by weight of secondary materials that interfere with the generation and/or emission of light at desired wavelengths other than tungsten-containing compounds.

The aluminum-borate NLO crystals described include, but are not limited to, aluminum-borate NLO crystals that have chemical structures comprising yttrium, lutetium, or combinations thereof, such as  $YAl_3(BO_3)_4$ ,  $LuAl_3(BO_3)_4$ , and  $Y_{(1-x)}Lu_xAl_3(BO_3)_4$ , where x is an integer greater than zero. These materials, when crystallized to crystal sizes useful for optical applications, are new compounds in so far as undesired contaminants that interfere with the generation and/or

emission of light at desired wavelengths are substantially reduced or substantially eliminated relative to known crystals.

Also described herein are embodiments of a method for making NLO crystals, particularly aluminum-borate NLO crystals. Some embodiments comprise providing a precursor materials and a solvent or a primary material and a solvent, where the solvent is substantially free of any materials that interfere with the generation and/or emission of light at desired wavelengths, and crystallizing the primary material to form a crystal that is substantially free of any materials that that interfere with the generation and/or emission of light at desired wavelengths. For example, the solvent and the crystal grown from the solvent can be substantially free of transitionmetal elements and lanthanides, other than yttrium, lanthanum, and lutetium. As another example, the solvent and the crystal grown from the solvent can be substantially free of molybdenum.

Embodiments of the method can comprise mixing the precursor materials or primary material with the solvent to form 20 a mixture and introducing a seed into the mixture. The seed, such as a crystalline primary material, perhaps consisting essentially of the primary material, can be suspended in the mixture. In some embodiments, recrystallizing the primary material comprises cooling the mixture and withdrawing the 25 crystal from the mixture. Cooling the mixture can comprise cooling the mixture from a first temperature at or above a melting point of the mixture to a second temperature below the melting point of the mixture over a growing period sufficient to grow crystals of a desired size suitable for useful 30 applications, such a growing period typically being longer than about 10 hours. During a portion of the growing period longer than about 2 hours, the mixture can be cooled at a cooling gradient of less than about 2° C. per hour. In some embodiments the second temperature can be, for example, a 35 temperature between about 5° C. and about 100° C. less than the melting point of the mixture.

The embodiments of the method can be used to grow a variety of NLO crystals, particularly aluminum-borate NLO crystals, such as aluminum-borate NLO crystals that have 40 chemical structures comprising yttrium, lutetium, or combinations thereof, such as YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>, LuAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>, and  $Y_{(1-x)}Lu_xAl_3(BO_3)_4$ , where x is an integer greater than zero. Suitable solvents include solvents substantially free of materials that interfere with the generation and/or emission of light 45 at desired wavelengths, including solvents that are substantially free of transition-metal elements and lanthanides, other than yttrium, lanthanum, and lutetium, and solvents that are substantially free of molybdenum. Examples of suitable solvents comprise one or more of the following compounds 50 LaB<sub>3</sub>O<sub>6</sub>, MgB<sub>2</sub>O<sub>4</sub>, and LiF. In some embodiments, the solvents are substantially free of transition-metal elements and lanthanides, other than yttrium, lanthanum, lutetium, and tungsten. An example of a tungsten-containing solvent is Li<sub>2</sub>WO<sub>4</sub>, which can be used, for example, with B<sub>2</sub>O<sub>3</sub> to grow 55 YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystals.

The described NLO crystals can be incorporated into a variety of devices, including laser devices. These devices can be used, for example, to detect anomalies on the surface of a substrate or to bore holes in a substrate.

### BRIEF DESCRIPTION OF THE DRAWINGS

FIG. 1 is a line graph showing the percent transmittance of a YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystal grown with tungsten (YAB—W), the 65 percent transmittance of a YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystal containing molybdenum (YAB—Mo), and the percent transmittance of a

4

 $YAl_3(BO_3)_4$  crystal that is substantially free of all transition-metal contaminants (YAB—La), over a wavelength range from 280 nm to 400 nm.

FIG. **2** is a schematic of a laser device that incorporates a NLO crystal.

## DETAILED DESCRIPTION OF THE INVENTION

### I. Abbreviations

mm: millimeters NLO: nonlinear optical nm: nanometers ppm: parts per million

SHG: second harmonic generation

## II. Terms

The following definitions are provided solely to aid readers and are intended to be no narrower than the meaning of the terms as they would be understood by a person of ordinary skill in the art.

Aluminum-Borate NLO Crystal: A NLO crystal with a chemical formula that includes aluminum and borate. Examples of aluminum-borate NLO crystals include, aluminum-borate NLO crystals that have chemical structures comprising yttrium, lutetium, or combinations thereof, such as YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>LuAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>, and Y<sub>(1-x)</sub>Lu<sub>x</sub>Al<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>, where x is an integer greater than zero.

Laser Beam: A beam of photons produced by a laser device. Laser beams can, for example, be substantially collimated, substantially monochromatic, and substantially coherent.

Molybdenum-Containing Compound: Elemental molybdenum or a compound with a chemical formula that includes molybdenum, such as molybdenum oxide.

Nonlinear Optical Crystal: A crystal that exhibits nonlinear polarization in response to light energy. These crystals comprise a primary material and can also comprise one or more secondary materials.

Primary Material: A crystalline compound having nonlinear optical properties. A primary material forms the bulk of the crystal lattice in a NLO crystal. Primary materials, as initially synthesized or isolated, typically exist in a powder form. The primary powder material must be recrystallized to form a NLO crystal of a suitable size and of a suitable purity for the generation and/or emission of light at a desired wavelength. Alternatively, the primary material can be formed from precursor materials during the crystallization process.

Precursor Material: A material that can be combined with other precursor materials to form a primary material. For example, Y<sub>2</sub>O<sub>3</sub>, B<sub>2</sub>O<sub>3</sub>, and Al<sub>2</sub>O<sub>3</sub> are precursor materials for the formation of YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>.

Secondary Material: Elements or compounds contained in a NLO crystal other than the primary material. Secondary materials can be incorporated intentionally (such as dopants) or incorporated unintentionally (such as contaminants). Secondary materials can be constituents of the crystal lattice or can exist outside the crystal lattice.

Transition-Metal Containing Compound: Elemental transition metals, or compounds with chemical formulas that include a transition metal, such as transition metal oxides.

Tungsten-Containing Compound: Elemental tungsten, or a compound with a chemical formula that includes tungsten, such as tungsten oxide.

# III. Nonlinear Optical Crystals and their Manufacture and Use

Described herein are embodiments of NLO crystals and embodiments of methods for making and using these crystals. 5 The described embodiments are useful for a variety of applications including, but not limited to, laser applications.

All NLO crystals comprise a crystal lattice having at least a primary material. NLO crystals also can include one or more secondary materials. The primary material can, for 10 example, be doped with various dopants to change the optical properties of the crystal. Examples of primary materials include, but are not limited to: YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>, LuAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>, BaB<sub>2</sub>O<sub>4</sub>, BaAl<sub>2</sub>B<sub>2</sub>O<sub>7</sub>, K<sub>2</sub>Al<sub>2</sub>B<sub>2</sub>O<sub>7</sub>, CaAl<sub>2</sub>B<sub>2</sub>O<sub>7</sub>, SrAl<sub>2</sub>B<sub>2</sub>O<sub>7</sub>, TiOPO<sub>4</sub>, KTiOAsO<sub>4</sub>, RbTiOPO<sub>4</sub>, RbTiOAsO<sub>4</sub>, CsTiOAsO<sub>4</sub>, LiNbO<sub>3</sub>, KNbO<sub>3</sub>, AgGaS<sub>2</sub>, AgGaSe<sub>2</sub>, KH<sub>2</sub>PO<sub>4</sub>, KD<sub>2</sub>PO<sub>4</sub>, NH<sub>4</sub>PO<sub>4</sub>, CsH<sub>2</sub>AsO<sub>4</sub>, CsD<sub>2</sub>AsO<sub>4</sub>, LilO<sub>3</sub>, and LiTaO<sub>3</sub>. These NLO materials may be used alone or in combination.

Among the aluminum-borate NLO crystals, aluminum-borate NLO crystals that have chemical structures comprising yttrium, lutetium, or combinations thereof, such as YAl<sub>3</sub> (BO<sub>3</sub>)<sub>4</sub>, LuAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>, and Y<sub>(1-x)</sub>Lu<sub>x</sub>Al<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>, where x is an integer greater than zero, are especially well-suited for the generation and/or emission of light at wavelengths shorter than about 300 nm, typically shorter than about 250 nm, typically less than about 200 nm, and even more typically shorter than about 175 nm.

The utility of NLO crystals, including aluminum-borate NLO crystals, is derived primarily from their optical properties. To achieve the desired optical properties, it is often necessary to grow a single crystal with a relatively continuous crystal structure and very few defects. Furthermore, most applications require that the single NLO crystal be a certain size, such as a size sufficient to make the crystal compatible with an optical device, for example, a laser. Some useful NLO crystals have a volume greater than about 0.1 mm³, typically greater than about 1 mm³, and even more typically greater than about 5 mm³.

Before primary materials are recrystallized to form single crystals of suitable size and purity, the primary material can exist in a powder form comprising amorphous material or very small crystals. The recrystallization process can begin with the primary material in power form or, alternatively, it can begin with precursor materials that can be combined to form the primary material. For example, it is possible to combine precursor materials with a solvent to form a mixture and then crystallize the primary material from that mixture. Useful precursor materials include oxides of each element in the chemical structure of a primary material. For example, for forming YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>, the precursor materials can include:  $Y_2O_3$ ,  $B_2O_3$ , and  $Al_2O_3$ . These precursor materials are available commercially, for example, from Sigma-Aldrich (St. Louis, Mo.).

This disclosure describes embodiments of a method for growing useful NLO crystals, such as aluminum-borate NLO crystals, from precursor materials or primary materials that are not yet in a form suitable for NLO crystal applications, i.e., are in their raw form, such as in powder form. Some embodiments involve mixing precursor materials or a primary material with a solvent to form a mixture. This mixture is then cooled and a NLO crystal grows as the mixture cools. The solvent provides a medium in which the elemental components of the primary material can combine in crystal form. Without a solvent, many primary materials, including YAl<sub>3</sub> (BO<sub>3</sub>)<sub>4</sub> and LuAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub>, tend to decompose unevenly at high temperatures.

Solvents can be chosen to promote the crystallization process by promoting the solubility of the precursor materials. 6 When the precursor materials are acidic, solubility is enhanced when the solvent is basic. Likewise, when the pre6

cursor materials are basic, solubility is enhanced when the solvent is acidic. The pH of the solvent can be adjusted to promote solubility, but extreme alkalinity or acidity may have a detrimental effect on crystal growth.

Conventionally, solvents were chosen solely for their effect on the crystallization process. Since the crystal separates from the solvent during the crystallization process, it was thought that the choice of solvent would have little or no effect on the crystals produced by the process. Surprisingly, it has been discovered that certain elements present in conventional solvents are incorporated into crystals grown from mixtures comprising these solvents. For example, YAl, (BO<sub>3</sub>)<sub>4</sub> crystals grown in K<sub>2</sub>MoO<sub>2</sub> contain molybdenum oxide as a secondary material. It has also been discovered that some of these contaminants, although present in small quantities, can substantially affect the optical properties of the crystals grown from mixtures comprising these solvents. For example, these contaminants can interfere with the generation and/or emission of light at desired wavelengths. Conventional YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystals contain contaminants that prevent the crystals from generating and/or emitting light at wavelengths less than 370 nm.

By growing crystals in a mixture free, or at least substantially free, of certain contaminants, it is possible to produce crystals with improved optical properties. For example, it is possible to grow aluminum-borate crystals, such as YAl<sub>3</sub> (BO<sub>3</sub>)<sub>4</sub> and LuAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystals, that generate and/or emit laser light at short wavelengths unobtainable with conventional aluminum-borate crystals, such as wavelengths less than about 250 nm, typically less than about 200 nm, and even more typically wavelengths less than about 175 nm.

Certain contaminants are more harmful to the optical properties of a NLO crystal than others. For example, some contaminants interfere with the generation and/or emission of light at short wavelengths, such as wavelengths less than about 300 nm, typically wavelengths less than about 250 nm, typically less than about 200 nm, and even more typically wavelengths less than about 175 nm. Some contaminants prevent NLO crystals from absorbing light at short wavelengths and therefore inhibit frequency mixing processes at these short wavelengths. Some of the contaminants that are incorporated into crystals grown in conventional solvents are compounds than contain elements that exhibit a charge transfer transition in the ultraviolet portion of the electromagnetic spectrum. These compounds interfere with the generation and/or emission of light at ultraviolet wavelengths. For some applications, the detrimental contaminants include compounds that contain transition-metal elements and/or lanthanides, other than yttrium, lanthanum, and lutetium. Table 1 shows the concentration of different elements in a YAl<sub>3</sub> (BO<sub>3</sub>)<sub>4</sub> crystal grown with a conventional solvent. As shown, the YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystal contains 250 ppm by weight of molybdenum.

TABLE 1

55	Compos	ition of a YA	Al <sub>3</sub> (BO <sub>3</sub> ) <sub>4</sub>	Crystal Grown w	ith a Conv	entional Solvent
	Element	ppm by weight	Element	ppm by weight	Element	ppm by weight
	Н	not tested	Zn	≤2	Pr	0.11
60	Li	0.15	Ga	≤1	Nd	~6000
	Be	< 0.01	Ge	< 0.1	Sm	0.1
	В	major	As	0.88	Eu	4.0
	C	not tested	Se	< 0.5	Gd	3.0
	N	not tested	Br	< 0.1	Tb	15
	O	major	Rb	< 0.1	Dy	0.10
55	F	< 0.5	Sr	0.37	Но	0.034
	Na	3.0	Y	major	Er	0.089

lengths.

	Composition of a YAl <sub>3</sub> (BO <sub>3</sub> ) <sub>4</sub> Crystal Grown with a Solvent Substantially Free of Molybdenum						
5	Element	ppm by weight	Element	ppm by weight	Element	ppm by weight	
	Ni Cu	0.15 0.50	La Ce	major 0.56	Th U	<0.01 <0.01	

Several crystal-growing techniques can be used in conjunction with the specially-selected solvents to produce NLO crystals with desirable properties. In some embodiments, the mixture formed by mixing the precursor materials and the solvent, or the primary material in its raw form and the solvent, is heated to a temperature above the melting point of the mixture. The melting point of the mixture varies depending on the type and quantity of the solvent and the type and quantity of the precursor materials or primary material. The melting point and other melt characteristics (such as melt viscosity and melt creeping) also can be varied by introducing various additives into the mixture. Some useful additives are alkali metal salts and alkaline-earth metal salts. These salts can be, for example, oxides, fluorides, or chlorides. The additives are selected so that they will not interfere with at least one, and perhaps plural desired optical properties of the crystal being formed. For example, additives for the formation of NLO crystals that are intended for second harmonic generation at short wavelengths are selected so that they will not prevent the crystal from absorbing light at these short wave-

In some embodiments of the crystal-growing process, a seed is introduced into the melted mixture and the mixture is then cooled slowly from a first temperature to a second temperature. The seed is typically a small crystal of the primary material, often with a crystal structure of uniform orientation. In some embodiments, the seed is suspended in the melted mixture as the mixture is cooled from the first temperature to the second temperature. As the mixture cools, the primary material crystallizes. The crystallization can occur around the seed as a single crystal with a uniform crystal orientation matching the crystal orientation of the seed.

Most of the crystal growth occurs over a growing period during which the mixture is cooled from the first temperature to the second temperature. The first temperature can be a temperature around or above the melting point of the mixture. The second temperature can be a temperature less than the melting point of the mixture, for example, a temperature between about 5° C. and about 100° C. less than the melting point of the mixture. The duration of the growing period depends on the primary material, the solvents, and the size of the desired crystal. Typically, crystals will grow at a rate of about 0.2 to about 0.3 mm per hour. Suitable growing periods are typically longer than about 10 hours. During a portion of the growing period, such as a portion longer than about 2 hours, the mixture can be cooled at a cooling gradient of less than about 2° C. per hour.

Table 3 lists several examples of mixtures containing different combinations of YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> (as the primary material) and solvents, along with key melt characteristics of the mixtures. For each mixture, Table 3 lists the melting point, the growing temperature range (i.e. the range between the first temperature and the second temperature), and an example of an appropriate growing period.

Composition of a YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> Crystal Grown with a Conventional Solvent

Element	ppm by weight	Element	ppm by weight	Element	ppm by weight
Mg	5.0	Zr	1.1	Tm	0.42
Al	major	Nb	0.079	Yb	< 0.1
Si	15	Mo	250	Lu	0.37
P	0.17	Ru	< 0.1	Hf	< 0.1
S	4.0	Rh	< 0.1	Ta	<10
C1	8.0	Pd	< 0.1	$W^*$	1.2
K	100	Ag	< 0.5	Re	< 0.1
Ca	6.0	Cd	< 0.5	Os	< 0.1
Sc	< 0.1	In	< 0.1	Ir	< 0.1
Ti	0.51	Sn	< 0.5	Pt	6.5
V	≤1	Sb	< 0.5	Au	<1
Cr	≤5	Te	< 0.1	Hg	< 0.1
Mn	0.37	I	< 0.1	Tl	< 0.1
Fe	10	Cs	< 0.1	Pb	< 0.1
Co	0.064	Ba	0.29	Bi	< 0.1
Ni	0.78	La	170	Th	< 0.01
Cu	1.0	Се	0.54	U	< 0.01

<sup>\*</sup>Inhomogeneous

In some of the disclosed embodiments, special solvents are used in the crystallization process. These solvents can be substantially free of contaminants that can be incorporated in growing crystals and can change the optical properties of those crystals. For example, these solvents can be substantially free of all transition-metal elements and lanthanides, other than yttrium, lanthanum, and lutetium. In some embodiments, these solvents are substantially free of molybdenum-containing compounds. In some embodiments, the solvent comprises LaB<sub>3</sub>O<sub>6</sub>, MgB<sub>2</sub>O<sub>4</sub>, LiF, or combinations thereof. The solvents LaB<sub>3</sub>O<sub>6</sub>, MgB<sub>2</sub>O<sub>4</sub>, and LiF are particularly useful for forming YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystals.

Table 2 shows the concentration of different elements in a  $YAl_3(BO_3)_4$  crystal grown in a solvent substantially free of molybdenum. As shown, the  $YAl_3(BO_3)_4$  crystal contains 0.15 ppm by weight of molybdenum.

TABLE 2

Composition of a YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> Crystal Grown

with a Solvent Substantially Free of Molybdenum						
Element	ppm by weight	Element	ppm by weight	Element	ppm by weight	
Н	Not tested	Zn	≤2	Pr	0.063	
Li	57	Ga	≤1	Nd	0.15	
Be	< 0.01	Ge	< 0.1	Sm	< 0.1	
В	major	As	< 0.5	Eu	< 0.1	
C	Not tested	Se	< 0.5	Gd	0.20	
N	Not tested	$_{\mathrm{Br}}$	< 0.1	Tb	0.038	
O	major	Rb	< 0.1	Dy	0.29	
F	< 0.5	Sr	0.066	Но	0.29	
Na	6.0	Y	major	Er	0.23	
Mg	3.0	Zr	0.41	Tm	0.013	
Al	major	Nb	0.14	Yb	1.9	
Si	75	Mo	0.15	Lu	0.083	
P	0.81	Ru	< 0.1	Hf	< 0.1	
S	16	Rh	< 0.1	Ta	<10	
C1	20	Pd	< 0.1	W	0.55	
K	4.0	Ag	< 0.5	Re	< 0.1	
Ca	2.5	Cd	< 0.5	Os	< 0.1	
Sc	< 0.1	In	< 0.1	Ir	< 0.1	
Ti	0.65	Sn	< 0.5	Pt	1.5	
V	≤1	Sb	< 0.5	Au	<1	
Cr	≤5	Te	< 0.1	Hg	< 0.1	
Mn	0.28	I	< 0.1	Tl	< 0.1	
Fe	10	Cs	< 0.1	Pb	< 0.1	
Co	< 0.1	Ba	0.15	Bi	< 0.1	

10
TABLE 4-continued

Mixture #	e Mixture	Melting Point (° C.)	Growing Temperature Range (° C.)	Growing Time (days)	5
1	YAl <sub>3</sub> (BO <sub>3</sub> ) <sub>4</sub> + 2LaB <sub>3</sub> O <sub>6</sub> +	1085	1085-1060	15	
2	LiF	1155	1155 1107	1.5	
2	$YAl_3(BO_3)_4 + 2LaB_3O_6$	1155	1155-1127	15	1
3	YAl <sub>3</sub> (BO <sub>3</sub> ) <sub>4</sub> + 1.5LaB <sub>3</sub> O <sub>6</sub> + LiF	1170	1170-1150	15	
4	$YAl_3(BO_3)_4 + 1.5LaB_3O_6$	1230	1230-1200	10	
5	YAl <sub>3</sub> (BO <sub>3</sub> ) <sub>4</sub> + LaB <sub>3</sub> O <sub>6</sub> + 2MgB <sub>2</sub> O <sub>4</sub>	1130	1130-1110	10	
6	$YAl_3(BO_3)_4 + 3Li_2WO_4 + 2B_2O_3$	1010	1010-920	30	1

Among the mixtures represented by Table 3, the crystals formed from mixtures 1-4 exhibited varying degrees of creeping. Crystals grown from mixture 5 exhibited less creeping.

Generally, for the growth of NLO crystals intended for SHG at short wavelengths, it is advantageous to select solvents that do not contain transition-metal elements and/or lanthanides, other than yttrium, lanthanum, and lutetium. However, some solvents containing transition metals are 25 especially effective at promoting melt uniformity of the primary material. It is therefore appropriate, in certain cases, to weigh the potential interference with the crystal's optical properties caused by possible incorporation of the harmful element into the NLO crystal with the beneficial effect of the solvent containing the harmful element. Use of solvents containing transition metals is especially appropriate where the NLO crystal being grown from the solvent is not intended to be used for SHG at very short wavelengths. For example, for the growth of NLO crystals to be used for SHG at wavelengths greater than about 300 nm, a solvent comprising tungsten can be used in some embodiments of the crystalgrowing process. One tungsten-containing solvent that is well-suited for the growth of YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystals is Li<sub>2</sub>WO<sub>4</sub>, 40 which can be used in conjunction with B<sub>2</sub>O<sub>3</sub>. Crystals grown from mixture 6 as recited in Table 4, which incorporates Li<sub>2</sub>WO<sub>4</sub> and B<sub>2</sub>O<sub>3</sub>, were of particularly high quality.

Table 4 shows the concentration of different elements in a YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystal grown from mixture 6 illustrated in Table 3. Tungsten was incorporated at 550 ppm by weight.

TABLE 4

Comp	Composition of a YAl <sub>3</sub> (BO <sub>3</sub> ) <sub>4</sub> Crystal Grown with Li <sub>2</sub> WO <sub>4</sub> and B <sub>2</sub> O <sub>3</sub>							
Element	ppm by weight	Element	ppm by weight	Element	ppm by weight			
Н	not tested	Zn	1.5	Pr	< 0.1			
Li	50	Ga	0.65	Nd	< 0.1			
Be	< 0.01	Ge	< 0.5	Sm	< 0.1			
В	Major	As	< 0.5	Eu	< 0.1			
С	not tested	Se	< 0.1	Gd	< 0.1			
N	not tested	$\operatorname{Br}$	< 0.1	Tb	< 0.1			
O	not tested	Rb	< 0.1	Dy	< 0.1			
F	< 0.5	Sr	not tested	Но	< 0.1			
Na	20	Y	major	Er	< 0.1			
Mg	7.5	Zr	0.067	Tm	< 0.1			
Al	major	Nb	< 0.05	Yb	< 0.1			
Si	50	Mo	0.15	Lu	< 0.1			
P	1.0	Ru	< 0.1	Hf	< 0.1			
S	5.0	Rh	< 0.1	Ta	<5			
Cl	50	Pd	< 0.1	W	550			
K	0.90	Ag	< 0.5	Re	< 0.1			
Ca	7.0	Cď	< 0.5	Os	< 0.1			

	Comp	osition of a	YAl <sub>3</sub> (BO <sub>3</sub>	)4 Crystal Grown	with Li <sub>2</sub> W	O <sub>4</sub> and B <sub>2</sub> O <sub>3</sub>
5	Element	ppm by weight	Element	ppm by weight	Element	ppm by weight
	Sc	≤0.5	In	< 0.1	Ir	<0.1
	Ti	0.75	Sn	0.30	Pt	< 0.5
	V	0.55	Sb	0.30	Au	< 0.5
	Cr	4.0	Te	< 0.5	Hg	< 0.1
0	Mn	0.055	I	< 0.1	Tl	< 0.1
	Fe	9.0	Cs	< 0.1	Pb	< 0.1
	Co	< 0.05	Ba	< 0.5	Bi	< 0.1
	Ni	0.15	La	not tested	Th	< 0.01
	Cu	0.60	Се	<0.1	U	< 0.01

In evaluating the effect of tungsten on the optical properties of a NLO crystal grown with a tungsten solvent, it is helpful to consider FIG. 1. FIG. 1 illustrates the percent transmittance of a YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystal grown with tungsten (YAB—W) compared to the percent transmittance of a YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystal containing molybdenum (YAB-Mo) and the percent transmittance of a YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystal that is substantially free of all transition-metal contaminants (YAB—La). As shown, the YAB—W crystal begins to absorb light at a wavelength that is longer than the wavelength at which the YAB—La crystal begins to absorb light, but shorter than the wavelength at which the YAB-Mo crystal begins to absorb light. For many applications, absorbance at shorter wavelengths is desirable. For these applications, the YAB—W crystal is preferable when compared to the YAB—Mo crystal, but still inferior to the YAB—La crystal.

After forming a crystal using the disclosed method, the uniform crystal structure can be verified by X-ray diffraction. The optical properties of the crystal can be tested by placing the crystal in a laser beam. For example, YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystals can be tested in this manner to confirm the production of second-harmonic light.

NLO crystals formed by the disclosed method include NLO crystals, such as aluminum-borate NLO crystals, that are substantially free and/or contain less than about 100 ppm by weight, typically less than about 50 ppm by weight, and even more typically less than about 10 ppm by weight of any element that interferes with the generation and/or emission of light at desired wavelengths, such as wavelengths less than about 300 nm, typically less than about 250 nm, typically less than about 200 nm, and even more typically less than about 175 nm. The secondary materials that interfere with the generation and/or emission of light at desired wavelengths can be, for example, transition-metal elements and lanthanides, 50 other than yttrium, lanthanum, and lutetium. The crystals also can be classified by their concentration of molybdenum-containing compounds. Some crystals formed by the disclosed method are substantially free and/or contain less than about 100 ppm by weight, typically less than about 50 ppm by 55 weight, and even more typically less than about 10 ppm by weight of any molybdenum-containing compound.

The crystals described in this disclosure have many useful applications. For example, aluminum-borate NLO crystals, such as aluminum-borate NLO crystals that have chemical structures comprising yttrium, lutetium, or combinations thereof, can be incorporated into laser devices, such as the laser device illustrated in FIG. 2. Under certain conditions, these crystals are capable of generating and/or emitting short wavelength laser beams.

Laser beams can be used to detect anomalies on the surface of substrates, including semiconductor substrates. This is done, for example, by directing the laser beam in a pattern

over the surface of the substrate, such as a raster pattern, and measuring the consistency of the reflected light. When the laser beam encounters an anomaly on the surface of the substrate, such as a particle, the reflected light will scatter. Shorter wavelength laser beams are especially useful because 5 they can detect smaller anomalies. This is important in the semiconductor industry, where, as the feature size decreases, the size of the anomalies that can adversely affect device function also decreases.

Shorter wavelength laser beams also can be used to bore 10 small diameter holes in substrates. These laser beams concentrate more energy in a smaller area than longer wavelength laser beams and are therefore able to impart more energy to the substrate. The ability to bore small diameter holes in a substrate is useful, for example, in the construction of features 15 on a printed circuit board.

Having illustrated and described several different embodiments of the invention, it should be apparent to those skilled in the art that the invention may be modified in arrangement and detail. We claim as our invention all such modifications as 20 come within the true spirit and scope of the following claims.

We claim:

- 1. A nonlinear optical crystal for use with a laser to generate a laser beam, the nonlinear optical crystal having a formula  $(Y_{1-x}Lu_x)Al_3(BO_3)_4$  where X=0-1, a volume greater than 25 about 0.1 mm³ and comprising less than about 100 ppm by weight of any element that inhibits the ability of the nonlinear optical crystal to generate and/or emit light at wavelengths less than about 300 nm.
- 2. The nonlinear optical crystal of claim 1, where the non-  $_{30}$  linear optical crystal has a formula  $LuAl_3(BO_3)_4$ .
- $3.\,\mathrm{A}$  nonlinear optical crystal for use with a laser to generate a laser beam, the nonlinear optical crystal having a formula  $\mathrm{YAl_3(BO_3)_4},$  a volume greater than about  $0.1~\mathrm{mm^3}$  and comprising less than about  $100~\mathrm{ppm}$  by weight of any element that  $_{35}$  inhibits the ability of the nonlinear optical crystal to generate and/or emit light at wavelengths less than about  $300~\mathrm{nm}.$
- 4. A YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> nonlinear optical crystal for use with a laser to generate a laser beam, the YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> nonlinear optical crystal having a volume greater than about 1 mm<sup>3</sup> and 40 being capable of converting an input laser beam of a first wavelength into an output laser beam of a second wavelength, where the second wavelength is less than about 200 nm.
- 5. The nonlinear optical crystal of claim 1 wherein the crystal is  $YAl_3(BO_3)_4$  doped with La or W.

12

- 6. A method of generating a laser beam, comprising:
- selecting a nonlinear optical crystal having a formula  $(Y_{1-x}Lu_x)Al_3(BO_3)_4$  where X=0-1, a volume greater than about 0.1 mm<sup>3</sup> and comprising less than about 100 ppm by weight of any element that inhibits the ability of the nonlinear optical crystal to generate and/or emit light at wavelengths less than about 300 nm; and
- directing an input laser beam at the nonlinear optical crystal to generate and/or emit an output laser beam exiting the nonlinear optical crystal, where the output laser beam has a wavelength less than about 300 nm.
- 7. The method of claim 6, where the nonlinear optical crystal is a YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystal doped with La or W.
- **8**. The method of claim **6**, where the nonlinear optical crystal is a YAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystal or a LuAl<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> crystal.
  - 9. A method, comprising:
  - directing an input laser beam at a nonlinear optical crystal to generate and/or emit an output laser beam having a wavelength less than about 300 nm, the nonlinear optical crystal having a formula  $(Y_{1-x}Lu_x)Al_3(BO_3)_4$  where X=0-1, a volume greater than about 0.1 mm³ and comprising less than about 100 ppm by weight of any element that inhibits the ability of the nonlinear optical crystal to generate and/or emit light at wavelengths less than about 300 nm; and

directing the output laser beam at a substrate to detect anomalies on the surface of the substrate.

10. A method, comprising:

directing an input laser beam at a nonlinear optical crystal to generate and/or emit an output laser beam having a wavelength less than about 300 nm, the nonlinear optical crystal having a formula (Y<sub>1-x</sub>Lu<sub>x</sub>Al<sub>3</sub>(BO<sub>3</sub>)<sub>4</sub> where X=0-1, volume greater than about 0.1 mm<sup>3</sup> and comprising less than about 100 ppm by weight of any element that inhibits the ability of the nonlinear optical crystal to generate and/or emit light at wavelengths less than about 300 nm; and

directing the output laser beam at a substrate to bore a hole in the substrate.

11. The  ${\rm YAl_3(BO_3)_4}$  nonlinear optical crystal according to claim 4 where the second wavelength is less than about 175 nm

\* \* \* \* \*